NSN 5962-01-420-4645

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Body	Length:
-	inches
Body	Width:
	inches
Body	Height:
	inches
Maxin	num Power Dissipation Rating:
1.0 wa	
Opera	ating Tempurature Range:
-55.0/	+125.0 degrees celsius
Stora	ge Tempurature Range:
-65.0/	+150.0 degrees celsius
End A	Application:
Pacer	dawn
Featu	res Provided:
Burn i	n and electrostatic sensitive and hermetically sealed and programmed and positive outputs and monolithic
Inclos	sure Material:
Ceran	nic and glass
Inclos	sure Configuration:
Leadle	ess flat pack
Outpu	ut Logic Form:
Trans	istor-transistor logic
Input	Circuit Pattern:
14 inp	put
Critic	ality Code Justification:
Cbbl	
Case	Outline Source And Designator:
C-2 m	il-m-38510
Termi	inal Surface Treatment:
Solde	r
Produ	uct Name:
Micro	circuit, programmed (pal 16r4a)
Volta	ge Rating And Type Per Characteristic:
7.0 vo	Its power source
Time	Rating Per Chacteristic:
30.00	nanoseconds propagation delay time, high to low level output and 30.00 nanoseconds propagation delay time, low to high level
output	t
Memo	bry Device Type:
Pal	
Speci	al Features:
Altere	d item, made from device p/n 81036102x, cage 67268, microcircuit, memory, programmable logic, monolithic silicon

Test Data Document:

96906-mil-std883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:

20 leadless

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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